Search update 10/781,746

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S21	9328	((326/107,117,120,93,72,108,121,81) or (327/201-203,208-218) or (716/17,6,2)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/20 08:10
S22	74	S21 and (manufacturing near step)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/20 08:19
S23	10	S22 and depletion and enhancement	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/20 08:23
S24	613	((manufacturing near step) or (manufacuring near process)) and depletion and enhancement	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/20 08:35
S25	243	S24 and replac$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/20 08:36
S26	44	S25 and (delay near time)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/20 08:36
S27	667	((fabricating near step) or (fabricating near process)) and depletion and enhancement	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/20 08:35
S28	274	S27 and replac$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/20 08:36
S29	23	S28 and (delay near time)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/20 08:36

Interference Search 10/781,746

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	((depletion-type adj MOSFET) and (enhancement-type adj MOSFET)).clm.	US-PGPUB	OR	ON	2005/09/22 16:23
L2	2	((depletion adj type adj MOSFET) and (enhancement adj type adj MOSFET)).clm.	US-PGPUB	OR	ON	2005/09/22 16:23

Interference Search 10/781,746